

Boosting Voltage Regulators

■ GENERAL DESCRIPTION

The XC62E series are a group of positive output voltage regulators that can supply up to 1A of output current using an external transistor. Low power and high accuracy are achieved through CMOS process and laser trimming technologies. The series consists of a high precision voltage reference, an error correction circuit and a short-circuit protected output driver. In stand-by mode, supply current can be dramatically cut. Since the input-output voltage differential is small, loss control efficiency is good.

The XC62E is particularly suited for use with battery operated portable products, and products where supply current regulation is required.

The series are available in an ultra small SOT-25 package.

In connection with the CE function, apart from the negative logic XC62EP series, a positive logic XC62ER series (custom) is also available.

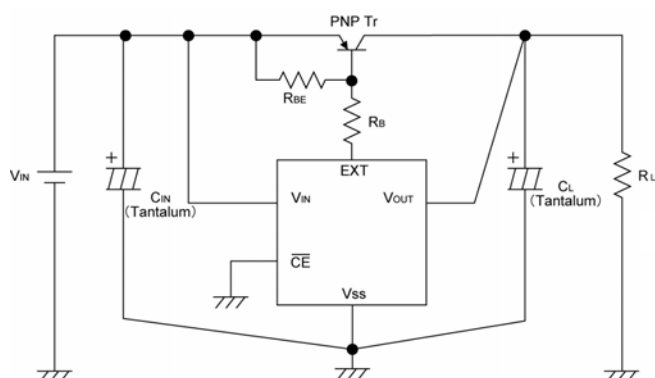
■ APPLICATIONS

- Portable cameras and video recorders
- Battery powered equipment
- Palmtops
- Reference voltage sources

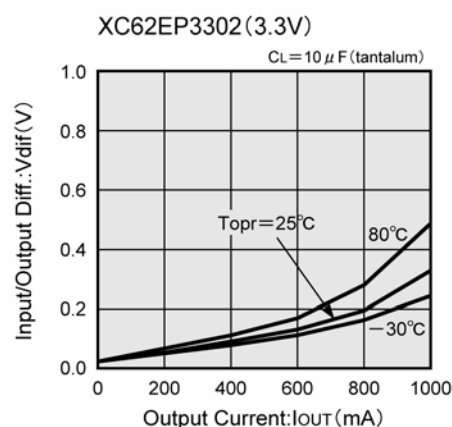
■ FEATURES

- Dropout Voltage** : 0.1A@100mA
(Performance depends on the external transistor characteristics.)
- Maximum Output Current** : 1000mA
- Output Voltage Range** : 1.5V~6.0V in 100mV increments
- Highly Accurate** : Setting voltage $\pm 2\%$
- Low Power Consumption**: 50 μ A ($V_{OUT}=5.0V$) (TYP.)
: 0.2 μ A (Stand-by) (TYP.)
- Output Voltage Temperature Characteristics**
: ± 100 ppm/ $^{\circ}C$ (TYP.)
- Line Regulation** : 0.1%/V (TYP.)
- CMOS Low Power Consumption**
- Ultra Small Package** : SOT-25 mini-mold

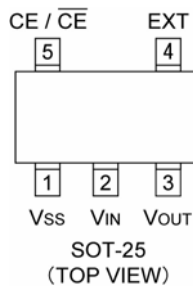
■ TYPICAL APPLICATION CIRCUIT



■ TYPICAL PERFORMANCE CHARACTERISTICS



PIN CONFIGURATION



PIN ASSIGNMENT

PIN NUMBER	PIN NAME	FUNCTION
1	V _{SS}	Ground
2	V _{IN}	Supply Voltage Input
3	V _{OUT}	Regulated Voltage Output
4	EXT	Base Current Control
5	CE/CE	Chip Enable

FUNCTION

SERIES	CE	OUTPUT VOLTAGE
XC62ER	H	ON
	L	OFF
XC62EP	H	OFF
	L	ON

H=High level

L=Low level

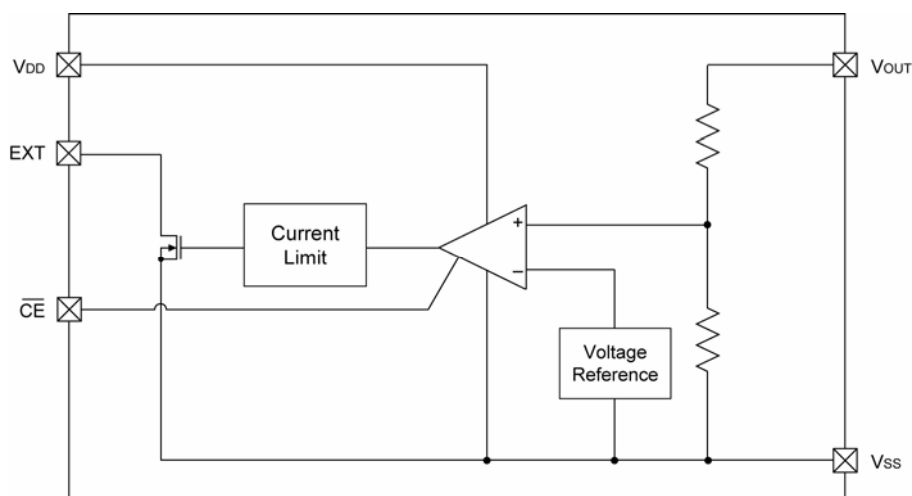
PRODUCT CLASSIFICATION

Ordering Information

XC62E①②③④⑤⑥⑦

DESIGNATOR	DESCRIPTION	SYMBOL	DESCRIPTION
①	CE Pin Logic	R	: Positive
		P	: Negative
② ③	Output Voltage	15 ~ 60	: e.g. V _{OUT} 1.5V→②=1, ③=5 V _{OUT} 6.0V→②=6, ③=0
④	Temperature Characteristics	0	: ±100ppm (TYP.)
⑤	Output Voltage Accuracy	2	: ±2%
⑥	Package	M	: SOT-25
⑦	Device Orientation	R	: Embossed tape, standard feed
		L	: Embossed tape, reverse feed

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

 $T_a = 25^{\circ}\text{C}$

PARAMETER	SYMBOL	RATINGS	UNITS
V_{IN} Input Voltage	V_{IN}	12.0	V
V_{OUT} Output Voltage	V_{OUT}	$V_{SS}-0.3 \sim V_{IN}+0.3$	V
$V_{CE}/\overline{CE}$ Input Voltage	V_{CE}	$V_{SS}-0.3 \sim V_{IN}+0.3$	V
EXT Output Voltage	V_{EXT}	12.0	V
EXT Output Current	I_{EXT}	50	mA
Power Dissipation	P_d	150	mW
Operating Temperature Range	T_{opr}	$-30 \sim +80$	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	$-40 \sim +125$	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS

XC62EP3002 $V_{OUT}(T)=3.0V$ ^(*1)

$T_a=25^{\circ}C$

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Output Voltage	$V_{OUT(E)}$ ^(*2)	$I_{OUT}=50mA$ $V_{IN}=4.0V$	2.940	3.000	3.060	V
Maximum Output Current*	$I_{OUT\ max}$	$V_{IN}=4.0V$	-	1000	-	mA
Load Regulation ^(*6)	ΔV_{OUT}	$V_{IN}=4.0V$ $1mA \leq I_{OUT} \leq 100mA$	-60	-	60	mV
Dropout Voltage ^(*3)	V_{dif}	$I_{OUT}=100mA$	-	100	-	mV
Supply Current 1	I_{SS1}	$V_{IN}=4.0V, V_{CE}=V_{SS}$	-	50	80	μA
Supply Current 2	I_{SS2}	$V_{IN}=8.0V, V_{CE}=V_{IN}$	-	-	0.6	μA
Line Regulation ^(*6)	$\frac{\Delta V_{OUT}}{\Delta V_{IN} \cdot V_{OUT}}$	$I_{OUT}=50mA$ $4.0V \leq V_{IN} \leq 8.0V$	-	0.1	0.3	%V
Input Voltage	ΔV_{IN}		-	-	8.0	V
Output Voltage Temperature Characteristics ^(*6)	$\frac{\Delta V_{OUT}}{\Delta T_{opr} \cdot V_{OUT}}$	$I_{OUT}=10mA$ $-30^{\circ}C \leq T_{opr} \leq 80^{\circ}C$	-	± 100	-	ppm/ $^{\circ}C$
EXT Output Voltage	V_{EXT}		-	-	8.0	V
EXT Leak Current	I_{LEAK}		-	-	0.5	μA
CE "High" Level Voltage	V_{CEH}		1.5	-	-	V
CE "Low" Level Voltage	V_{CEL}		-	-	0.25	V
CE "High" Level Current	I_{CEH}	$V_{CE}=V_{IN}$	-	-	0.1	μA
CE "Low" Level Current	I_{CEL}	$V_{CE}=V_{SS}$	-0.2	-0.05	0	μA

The characteristics for the XC62ER series are the same as above except for the CE operating logic, which is the opposite.

NOTE:

- *1: $V_{OUT}(T)$ =Specified output voltage.
- *2: $V_{OUT(E)}$ =Effective output voltage (i.e. the output voltage when " $V_{OUT}(T)+1.0V$ " is provided at the V_{IN} pin while maintaining a certain I_{OUT} value).
- *3: $V_{dif} = \{V_{IN1}^{(*5)} - V_{OUT1}^{(*4)}\}$
- *4: V_{OUT1} = A voltage equal to 98% of the output voltage whenever an amply stabilized I_{OUT} $\{V_{OUT}(T)+1.0V\}$ is input.
- *5: V_{IN1} =The input voltage when V_{OUT1} appears as input voltage is gradually decreased.
- *6: The characteristics for the parameters are liable to vary depending on which transistor is used.
Please use a transistor with a low saturation voltage level and hFE equal to 100 or more.
- *7: The maximum output current value is not a value representing continuous output due to the limitations of the 2AS1213 transistor's power dissipation.

ELECTRICAL CHARACTERISTICS (Continued)

XC62EP4002

VOUT(T)=4.0V(*1)

Ta=25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Output Voltage	V _{OUT(E)} (*2)	I _{OUT} =50mA V _{IN} =5.0V	3.920	4.000	4.080	V
Maximum Output Current (*6)	I _{OUT max}	V _{IN} =5.0V	-	1000	-	mA
Load Regulation (*6)	ΔV _{OUT}	V _{IN} =5.0V 1mA ≤ I _{OUT} ≤ 100mA	-60	-	60	mV
Dropout Voltage (*3)	V _{dif}	I _{OUT} =100mA	-	100	-	mV
Supply Current 1	I _{SS1}	V _{IN} =5.0V, V _{CE} =V _{SS}	-	50	80	μA
Supply Current 2	I _{SS2}	V _{IN} =8.0V, V _{CE} =V _{IN}	-	-	0.6	μA
Line Regulation (*6)	$\frac{\Delta V_{OUT}}{\Delta V_{IN} \cdot V_{OUT}}$	I _{OUT} =50mA 5.0V ≤ V _{IN} ≤ 8.0V	-	0.1	0.3	%V
Input Voltage	V _{IN}		-	-	8.0	V
Output Voltage Temperature Characteristics (*6)	$\frac{\Delta V_{OUT}}{\Delta T_{opr} \cdot V_{OUT}}$	I _{OUT} =10mA -30°C ≤ T _{opr} ≤ 80°C	-	±100	-	ppm/°C
EXT Output Voltage	V _{EXT}		-	-	8.0	V
EXT Leak Current	I _{LEAK}		-	-	0.5	μA
$\overline{CE}$ "High" Level Voltage	V _{CEH}		1.5	-	-	V
$\overline{CE}$ "Low" Level Voltage	V _{CEL}		-	-	0.25	V
$\overline{CE}$ "High" Level Current	I _{CEH}	V _{CE} =V _{IN}	-	-	0.1	μA
$\overline{CE}$ "Low" Level Current	I _{CEL}	V _{CE} =V _{SS}	-0.2	-0.05	0	μA

XC62EP4002

VOUT(T)=5.0V(*1)

Ta=25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Output Voltage	V _{OUT(E)} (*2)	I _{OUT} =50mA V _{IN} =6.0V	4.940	5.000	5.100	V
Maximum Output Current (*6)	I _{OUT max}	V _{IN} =6.0V	-	1000	-	mA
Load Regulation (*6)	ΔV _{OUT}	V _{IN} =6.0V 1mA ≤ I _{OUT} ≤ 100mA	-60	-	60	mV
Dropout Voltage (*3)	V _{dif}	I _{OUT} =100mA	-	100	-	mV
Supply Current 1	I _{SS1}	V _{IN} =6.0V, V _{CE} =V _{SS}	-	50	80	μA
Supply Current 2	I _{SS2}	V _{IN} =8.0V, V _{CE} =V _{IN}	-	-	0.6	μA
Line Regulation (*6)	$\frac{\Delta V_{OUT}}{\Delta V_{IN} \cdot V_{OUT}}$	I _{OUT} =50mA 6.0V ≤ V _{IN} ≤ 8.0V	-	0.1	0.3	%V
Input Voltage	V _{IN}		-	-	8.0	V
Output Voltage Temperature Characteristics (*6)	$\frac{\Delta V_{OUT}}{\Delta T_{opr} \cdot V_{OUT}}$	I _{OUT} =10mA -30°C ≤ T _{opr} ≤ 80°C	-	±100	-	ppm/°C
EXT Output Voltage	V _{EXT}		-	-	8.0	V
EXT Leak Current	I _{LEAK}		-	-	0.5	μA
$\overline{CE}$ "High" Level Voltage	V _{CEH}		1.5	-	-	V
$\overline{CE}$ "Low" Level Voltage	V _{CEL}		-	-	0.25	V
$\overline{CE}$ "High" Level Current	I _{CEH}	V _{CE} =V _{IN}	-	-	0.1	μA
$\overline{CE}$ "Low" Level Current	I _{CEL}	V _{CE} =V _{SS}	-0.2	-0.05	0	μA

The characteristics for the XC62ER series are the same as above except for the CE operating logic, which is the opposite.

Note: *1. VOUT(T)=Specified output voltage.

*2. VOUT(E)=Effective output voltage (i.e. the output voltage when "VOUT(T)+1.0V" is provided at the VIN pin while maintaining a certain IOUT value).

*3. Vdif= {VIN1 (*5)-VOUT1 (*4)}

*4. VOUT1= A voltage equal to 98% of the output voltage whenever an amply stabilized IOUT {VOUT(T)+1.0V} is input.

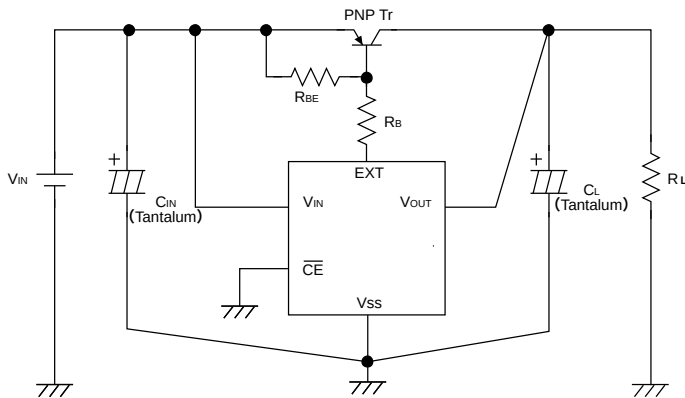
*5. VIN1= The input voltage when VOUT1 appears as input voltage is gradually decreased.

*6. The characteristics for the parameters are liable to vary depending on which transistor is used.
Please use a transistor with a low saturation voltage level and hFE equal to 100 or more.

*7. The maximum output current value is not a value representing continuous output due to the limitations of the 2AS1213 transistor's power dissipation.

TYPICAL APPLICATION CIRCUIT

●Standard Circuit



External Components:

PNP Tr.: 2SA1213

R_{BE}: 20kΩ ~ 47kΩ

R_B: Please refer to Note 2 on the following page.

C_{IN}: 10μF (Tantalum)

C_L: 47μF (Tantalum) 10μF minimum

OPERATIONAL EXPLANATION

Output voltage (V_{OUT}) can be fixed by revising the external transistor's base current. This can be done by comparing the detected voltage level and the setting voltage power supply level.

With the XC62EP (CE negative voltage), if a voltage above the CE pin's "H" level is applied, the IC will enter stand-by mode where the base and differential amplifier's currents are regulated.

NOTES ON USE

1. PNP Transistor

The selection of a transistor should take into account output current, input voltage and power dissipation for each specific application. It is recommended that a transistor that has a low output saturated voltage (V_{CE}) and high h_{FE} characteristics be used.

2. R_B Resistor

Although the IC unit is protected by a base current remitter circuit, it is recommended that a resistor (R_B) be connected between the transistor's base and the IC's EXT pin to protect the transistor.

Required output current can be calculated using the following equation although characteristic variations and conditions of use should be carefully checked before use. The following equation also indicates the conditions needed to obtain I_{OUT} (MAX.) at V_{IN} (MIN.). However, the larger the input current, the larger the output current (I_{OUT}) that can be obtained.

$$\frac{V_{IN} (MIN.) - 1.2(V)}{R_B} - \frac{0.7(V)}{R_{BE}} > \frac{I_{OUT} (MAX.)}{hFE}$$

3. R_{BE} Resistor, C_L Capacitor

To prevent oscillation due to output load variation, use of a phase compensation capacitor C_L is recommended. Please use a Tantalum capacitor of at least 10mF. Please also use an R_{BE} resistor of less than 47kΩ.

An R_{BE} resistor of between 20kΩ and 47kΩ is recommended for less power consumption.

4. Input Impedance

In order to control oscillation brought about as a result of impedance at the power supply line, connect a capacitor of 10μF or more (Tantalum) between the external transistor's emitter and the ground pin.

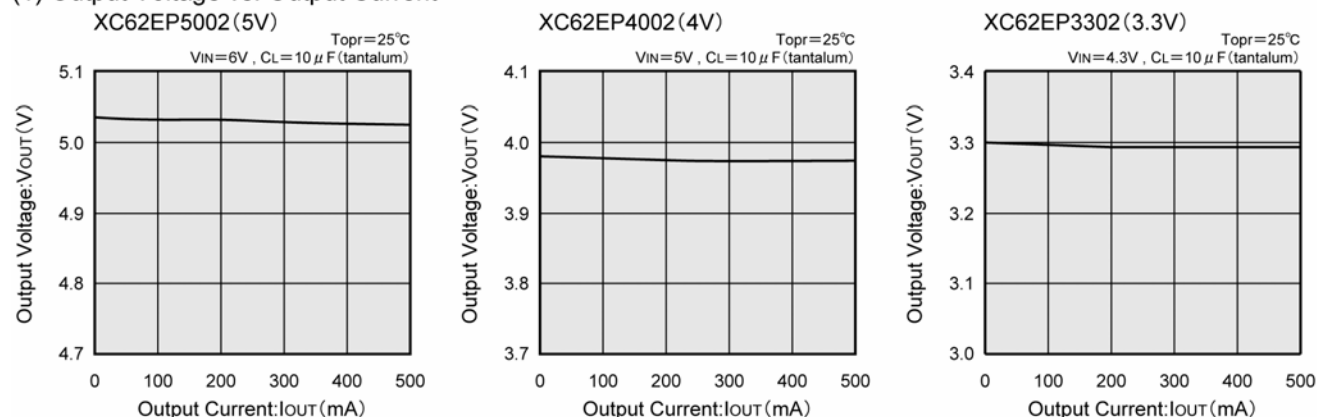
●Protection Circuit

The built-in protection circuit is to protect the IC only. Therefore to prevent output shorts and overshoot current through the transistor, use of a resistor R_B or an overshoot current protection circuit is recommended.

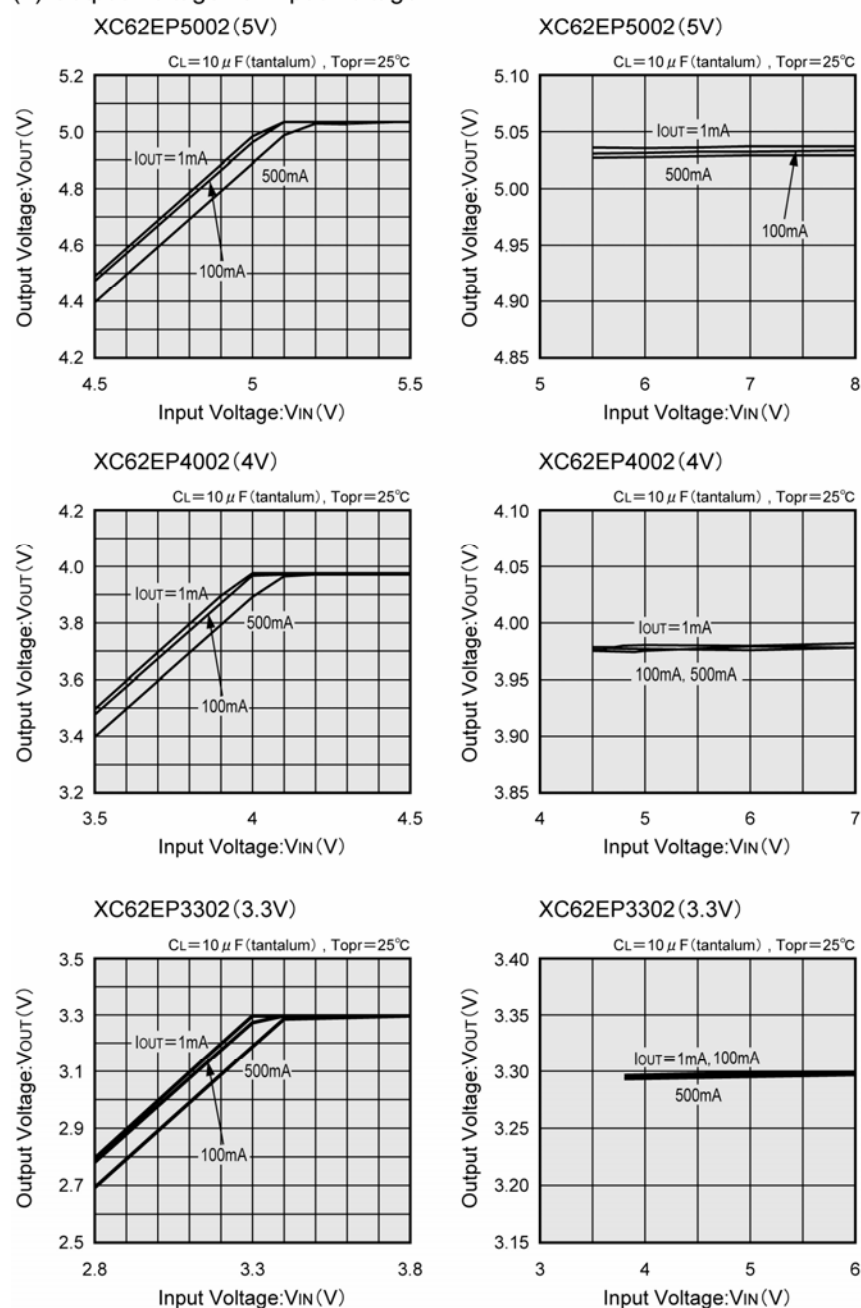
Care should also be taken with the transistor's power dissipation.

TYPICAL PERFORMANCE CHARACTERISTICS

(1) Output Voltage vs. Output Current



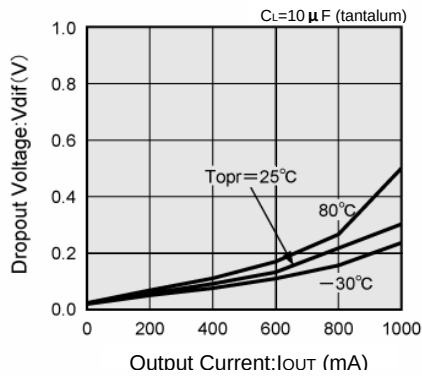
(2) Output Voltage vs. Input Voltage



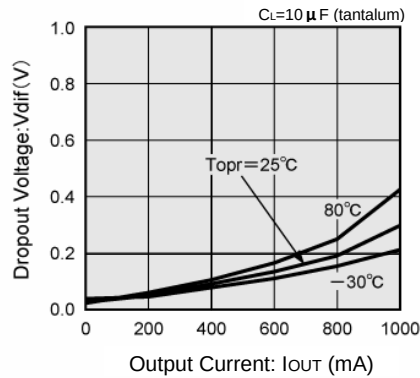
TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(3) Dropout Voltage vs. Output Current

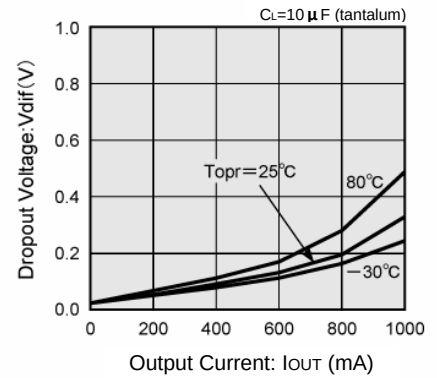
XC62EP5002 (5V)



XC62EP4002 (4V)

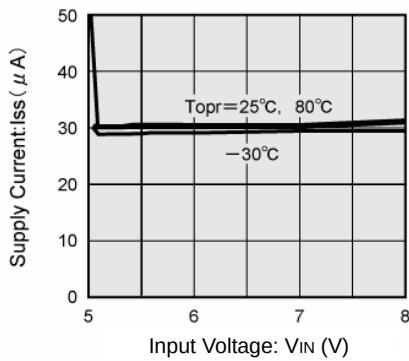


XC62EP3302 (3.3V)

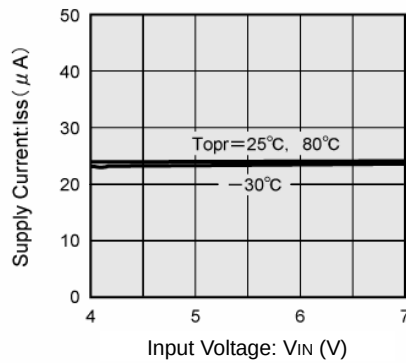


(4) Supply Current vs. Input Voltage

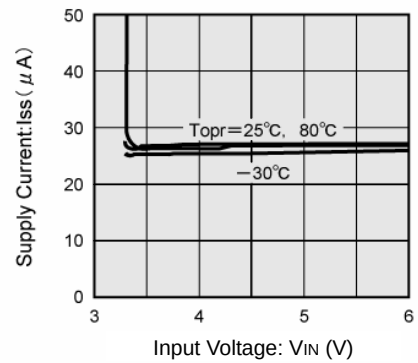
XC62EP5002 (5V)



XC62EP4002 (4V)

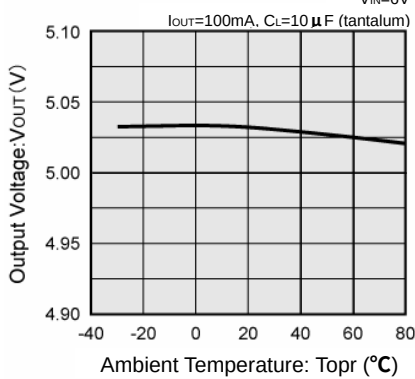


XC62EP3302 (3.3V)

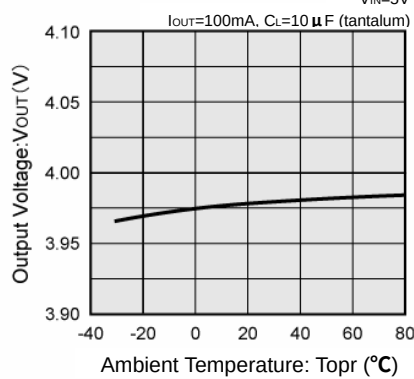


(5) Output Voltage vs. Ambient Temperature

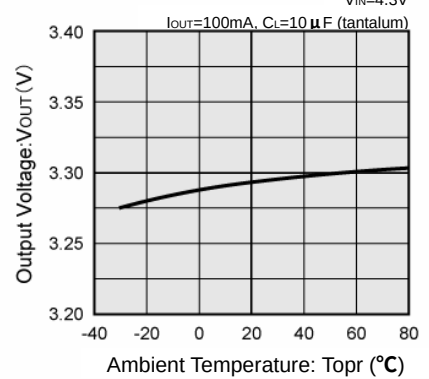
XC62EP5002 (5V)



XC62EP4002 (4V)

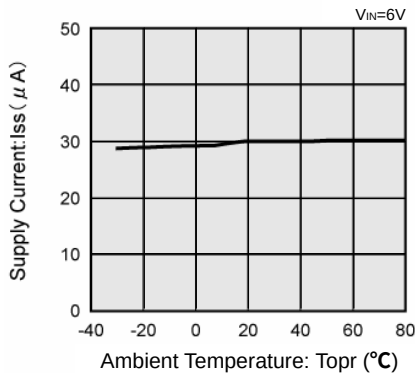


XC62EP3302 (3.3V)

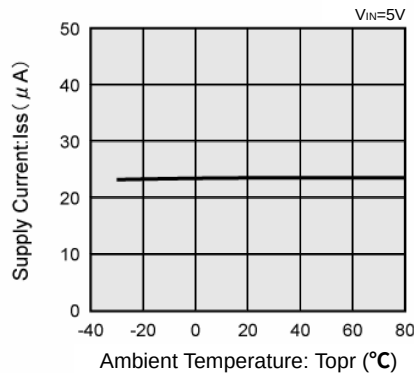


(6) Supply Current vs. Ambient Temperature

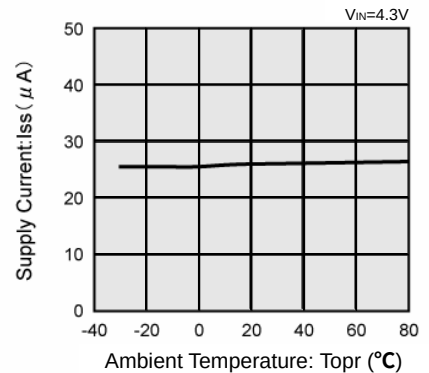
XC62EP5002 (5V)



XC62EP4002 (4V)

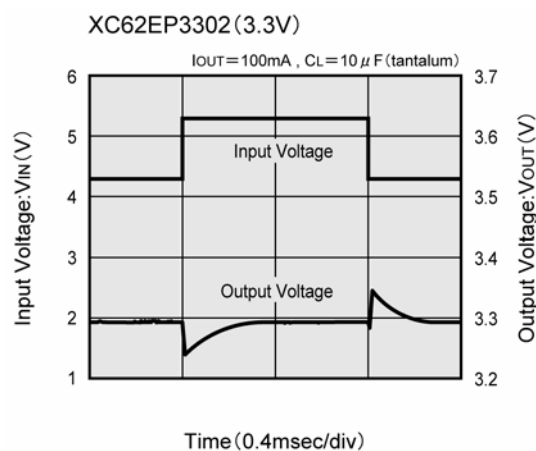
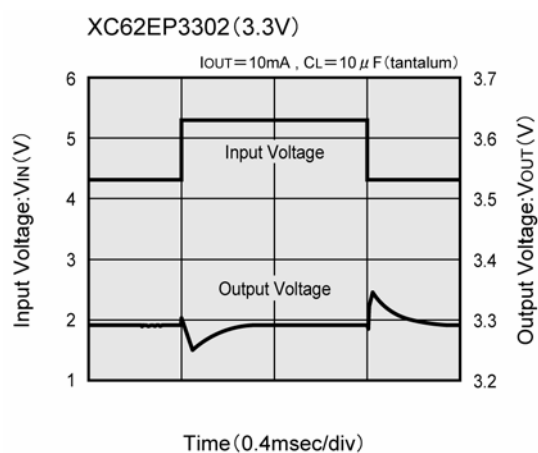
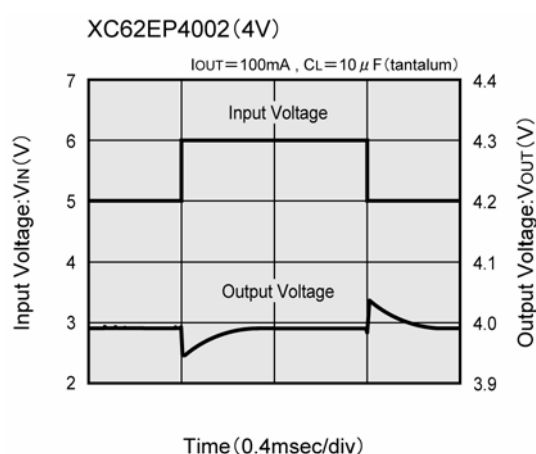
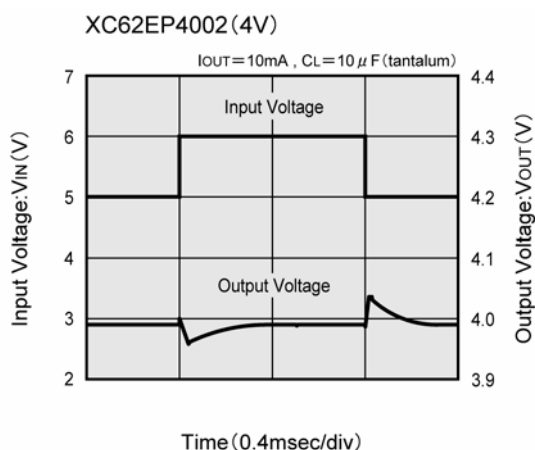
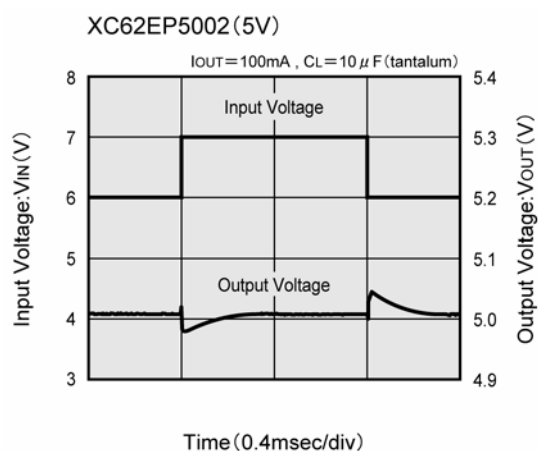
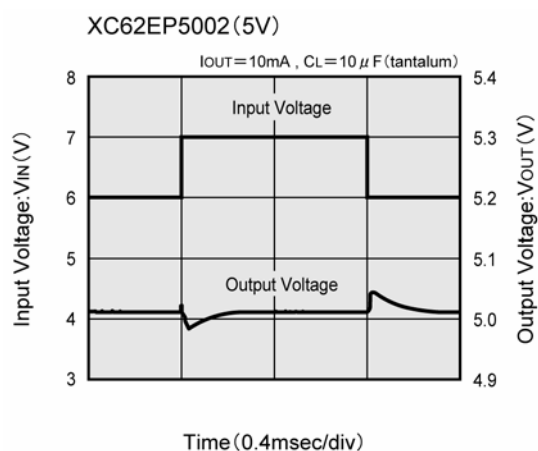


XC62EP3302 (3.3V)



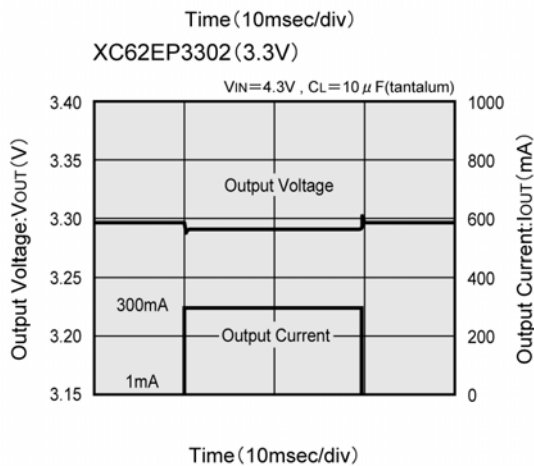
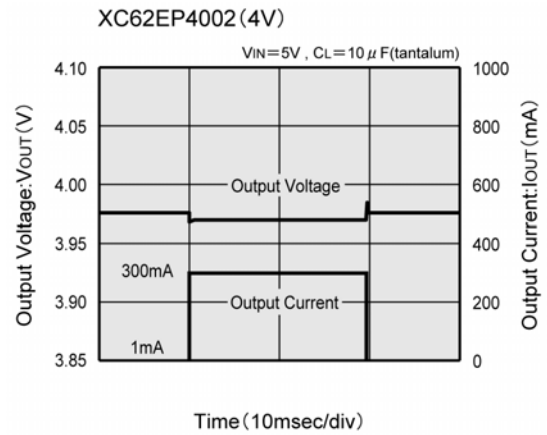
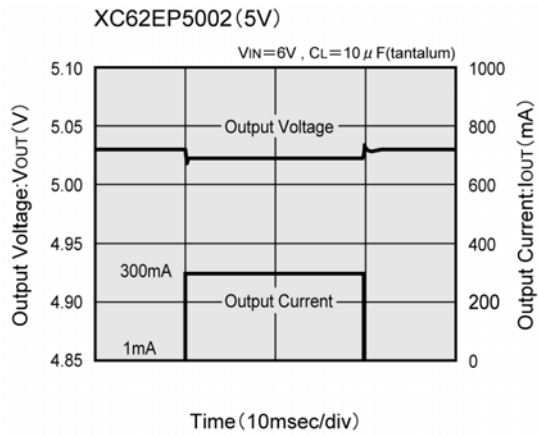
■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(7) Input Transient Response

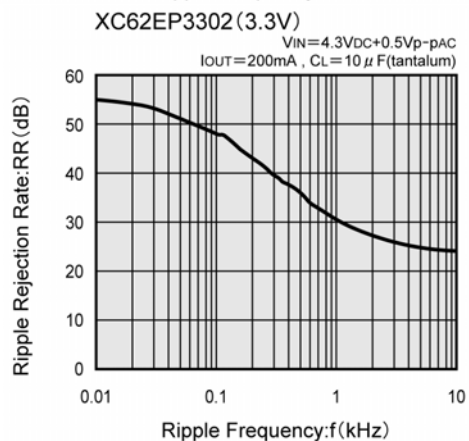
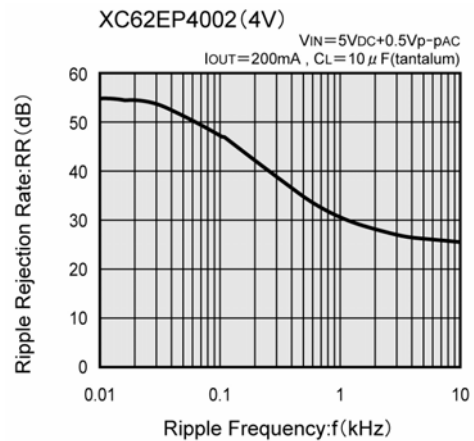
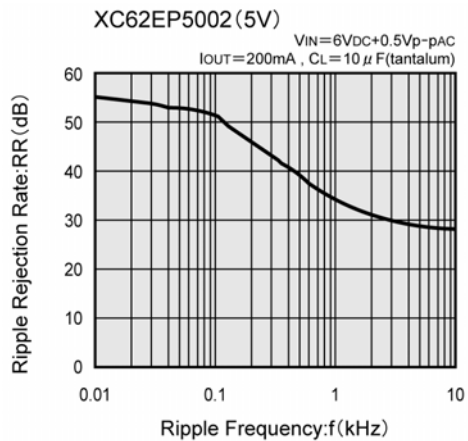


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(8) Load Transient Response

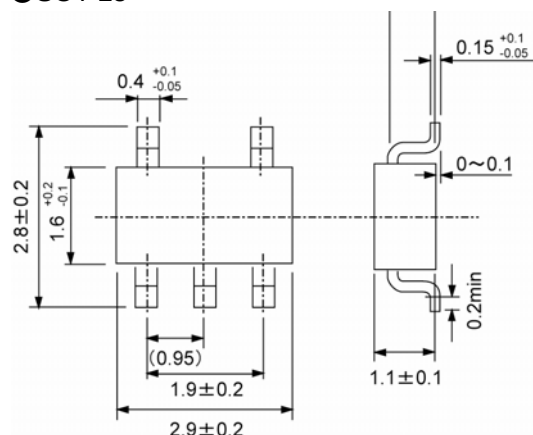


(9) Ripple Rejection Rate



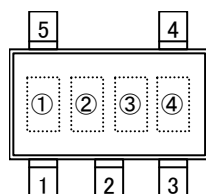
PACKAGING INFORMATION

● SOT-25



MARKING RULE

● SOT-25



SOT-25
(TOP VIEW)

① Not used

② Represents integer of output voltage

MARK (XC62ER Type)	VOLTAGE (V)	MARK (XC62EP Type)	VOLTAGE (V)
2	2.x	2	2.x
3	3.x	3	3.x
4	4.x	4	4.x
5	5.x	5	5.x
6	6.x	6	6.x

③ Represents decimal number of output voltage

MARK (XC62ER Type)	VOLTAGE (V)	MARK (XC62EP Type)	VOLTAGE (V)
0	x.0	0	x.0
1	x.1	1	x.1
2	x.2	2	x.2
3	x.3	3	x.3
4	x.4	4	x.4
5	x.5	5	x.5
6	x.6	6	x.6
7	x.7	7	x.7
8	x.8	8	x.8
9	x.9	9	x.9

④ Based on internal standards

1. The products and product specifications contained herein are subject to change without notice to improve performance characteristics. Consult us, or our representatives before use, to confirm that the information in this catalog is up to date.
2. We assume no responsibility for any infringement of patents, patent rights, or other rights arising from the use of any information and circuitry in this catalog.
3. Please ensure suitable shipping controls (including fail-safe designs and aging protection) are in force for equipment employing products listed in this catalog.
4. The products in this catalog are not developed, designed, or approved for use with such equipment whose failure of malfunction can be reasonably expected to directly endanger the life of, or cause significant injury to, the user.
(e.g. Atomic energy; aerospace; transport; combustion and associated safety equipment thereof.)
5. Please use the products listed in this catalog within the specified ranges.
Should you wish to use the products under conditions exceeding the specifications, please consult us or our representatives.
6. We assume no responsibility for damage or loss due to abnormal use.
7. All rights reserved. No part of this catalog may be copied or reproduced without the prior permission of Torex Semiconductor Ltd.

TOREX SEMICONDUCTOR LTD.